

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	578	326/30.ccls. and (mosfet or fet or mos or nmos or pmos or mesfet or misfet) and (gate) and (source or drain) and (resistor or resistance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 10:16
L2	256	326/30.ccls. and (mosfet or fet or mos or nmos or pmos or mesfet or misfet) and (gate) and (source or drain) and (resistor or resistance) and (amplifier or op-amp or differential near amp)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 10:27
L4	6	("5243229" "5666078" "6002354" "6188237" "6522175" "6570402").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/28 10:47
L5	3	("5726582" "6288564" "6414512").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/28 11:45
L7	17	odt near6 (fet or mosfet or mos or nmos or pmos)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/28 11:45
S1	187	(termination or terminator or resistance near match\$4 or impedance near match\$3) near4 (resistor or linear or linearity) same (gate and source and drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/28 10:14
S2	120	(on-die) near3 (termination or matching)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/30 14:35
S3	14	"6429685".pn. "6560290".pn. "6525558".pn. "5680060".pn. "6424169".pn. "5329190".pn. "6362655".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/03 11:03
S4	5	("4469961" "5254883" "5767703" "5898321" "6236246").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 08:34
S5	19	("5329190").URPN.	USPAT	OR	ON	2005/10/14 09:25
S6	183	(active) near (termination or terminator) and (mos or mosfet or pmos or nmos) and (resistor or resistance or impedance)	USPAT	OR	ON	2005/10/14 10:22
S7	27	(dynamic or dynamically) near (termination or terminator) and (mos or mosfet or pmos or nmos) and (resistor or resistance or impedance) not S6	USPAT	OR	ON	2005/10/14 10:27
S8	317	((("on-die" or "on die" or "on-chip" or "on chip") near3 (termination or matching or terminator)) and (mos or mosfet or gate or drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/14 14:17
S9	5	("4469961" "5254883" "5767703" "5898321" "6236246").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 14:57
S10	15	(active or dynamic) near2 resistor near9 (third or three) near3 (mosfet or transistor or fet or nmos or pmos)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:13
S11	276	(termination or terminating or terminator or matching) near3 (resistor or resistance or impedance) and (third or three or tertiary) near3 (mos or mosfet or transistor or nmos or pmos) same resistor near6 (gate or source or drain)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:16

S12	498	(termination or terminating or terminator or matching) near3 (resistor or resistance or impedance) and (third or three or tertiary) near3 (mos or mosfet or transistor or nmos or pmos) near8 (resistor)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:16
S13	131	(termination or terminating or terminator or matching) near3 (resistor or resistance or impedance) and (third or three or tertiary) near3 (mos or mosfet or transistor or nmos or pmos) near8 (resistor) near5 (source or gate or drain)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:27
S14	238	257/350.cor.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:40
S15	33	257/363.cor.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:42
S16	155	257/379.cor.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 15:56
S17	50	257/380.cor.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 16:04
S18	589	326/30.cor.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/14 16:36
S19	86	326/30.cor. and (mos or mosfet or nmos or pmos) near8 (source or gate or drain) near8 (resistor or impedance)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/27 16:11
S20	5	("5227677" "6100713" "6127840" "6239619" "6275088"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/27 15:21
S21	3782	(impedance near matching) same (mos or mosfet or nmos or pmos or fet or transistor)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/27 15:22
S22	385	(impedance near matching) near10 (mos or mosfet or nmos or pmos or fet or transistor) near10 (resistor or resistance or resistive)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/27 16:06
S23	1	(odt or on-die-termination) near2 (resistor) near8 (linear or linearity or linearly)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/27 16:07
S24	7	(odt or on-die-termination) near2 (resistor) and (linear or linearity or linearly)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:09
S25	14	(odt or on-die-termination) near5 (fet or mosfet or nmos or pmos or mos)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:10
S26	422	326/83.cor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:10
S27	46	326/83.cor. and (mos or mosfet or nmos or pmos) near8 (source or gate or drain) near8 (resistor or impedance)	US-PGPUB; USPAT; USOCR	OR	ON	2005/10/27 16:42

S28	2177	(termination or terminator or terminating or output or input or matching) near (circuit or network) same (third or plural or plurality or multiple or multi or several) near2 (transistor or fet or mosfet or mos or nmos or pmos) and (resistor or resistance) near4 (gate or source)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:44
S29	39	(termination or terminator or terminating or output or input or matching) near (circuit or network or resistor) same (third or plural or plurality or multiple or multi or several) near2 (transistor or fet or mosfet or mos or nmos or pmos) and (resistor or resistance) near4 (gate or source) and (linear or linearity or linearly) near4 (current near voltage or current near bias or iv or vi or i near v)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:53
S30	4403	(termination or terminator or terminating or output or input or matching) near (circuit or network or resistor) same (transistor or fet or mosfet or mos or nmos or pmos) and (resistor or resistance) near4 (gate or source) and (differential near amplifier)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:54
S31	66	(termination or terminator or terminating or output or input or matching) near (circuit or network or resistor) near10 (linear or linearity or linearly) same (transistor or fet or mosfet or mos or nmos or pmos) and (resistor or resistance) near4 (gate or source) and (differential near amplifier)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:54
S32	39	(termination or terminator or terminating or output or input or matching) near (circuit or network or resistor) near10 (linear or linearity or linearly) same (transistor or fet or mosfet or mos or nmos or pmos) same (resistor or resistance) same (gate or source) and (differential near amplifier)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/10/27 16:54